



Voltage Detectors , ME2808 Series

General Description

ME2808 Series are a set of three-terminal low power voltage detectors implemented in NMOS technology. Each voltage detector in the series detects a particular fixed voltage ranging from 2.0V to 7.0V. The voltage detectors consist of a high precision and low power consumption standard voltage source, a comparator, hysteresis circuit, and an output driver. NMOS technology ensures low power consumption.

Features

- Highly accuracy: $\pm 1\%$
- Low power consumption: TYP 1.8uA ($V_{in}=3V$)
- Detect voltage range : 2.0V~7.0V in 0.1V increments
- Operating voltage range: 1.5V~18V
- Detect voltage temperature characteristics:
TYP $\pm 0.9mV/^{\circ}C$
- Output configuration: NMOS
- Package: SOT23, SOT23-3, SOT23-5, SOT89-3, TO-92

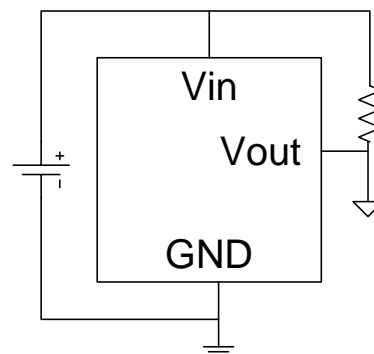
Typical Application

- battery checkers
- Level selectors
- Power failure detectors
- Microcomputer reset
- Battery backup of Memories
- Store non-volatile RAM signal protectors

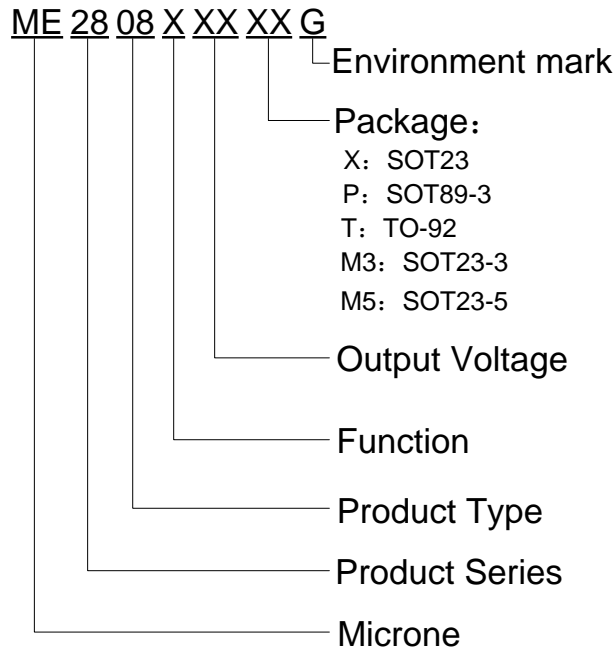
Package

- 3-pin SOT23、SOT23-3、SOT89-3、TO-92
- 5-pin SOT23-5

Typical Application Circuit



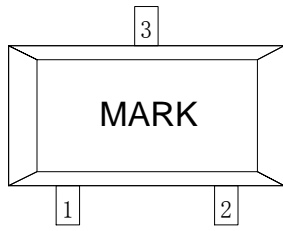
Selection Guide



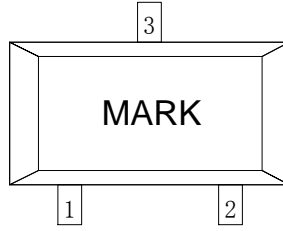
product series	product description
ME2808A25XG	$V_{OUT} = 2.5V$; Rising edge detection; Package: SOT23
ME2808A36XG	$V_{OUT} = 3.6V$; Rising edge detection; Package: SOT23
ME2808A22M3G	$V_{OUT} = 2.2V$; Rising edge detection; Package: SOT23-3
ME2808A33M3G	$V_{OUT} = 3.3V$; Rising edge detection; Package: SOT23-3
ME2808A60M3G	$V_{OUT} = 6.0V$; Rising edge detection; Package: SOT23-3
ME2808A30PG	$V_{OUT} = 3.0V$; Rising edge detection; Package: SOT89-3
ME2808A27TG	$V_{OUT} = 2.7V$; Rising edge detection; Package: TO-92
ME2808A42M5G	$V_{OUT} = 4.2V$; Rising edge detection; Package: SOT23-5
ME2808B28M3G	$V_{OUT} = 2.8V$; Falling edge detection; Package: SOT23-3

NOTE: At present ,there are eighteen kinds of voltage value: 2.2V、2.4V、2.5V、2.7V、2.8V、3.0V、3.2V、3.3V、3.5V、3.6V、3.8V、3.9V、4.0V、4.2V、4.3V、4.5V、5.0V、6.0V。If you need other voltage and package, please contact our sales staff.

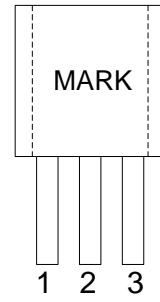
Pin Configuration



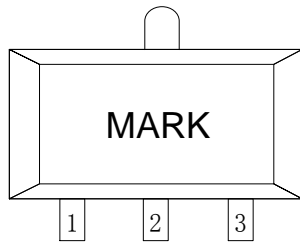
SOT23



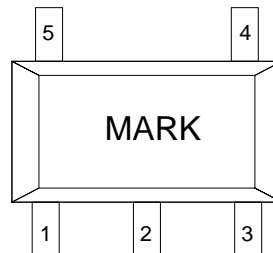
SOT23-3



TO-92



SOT89-3

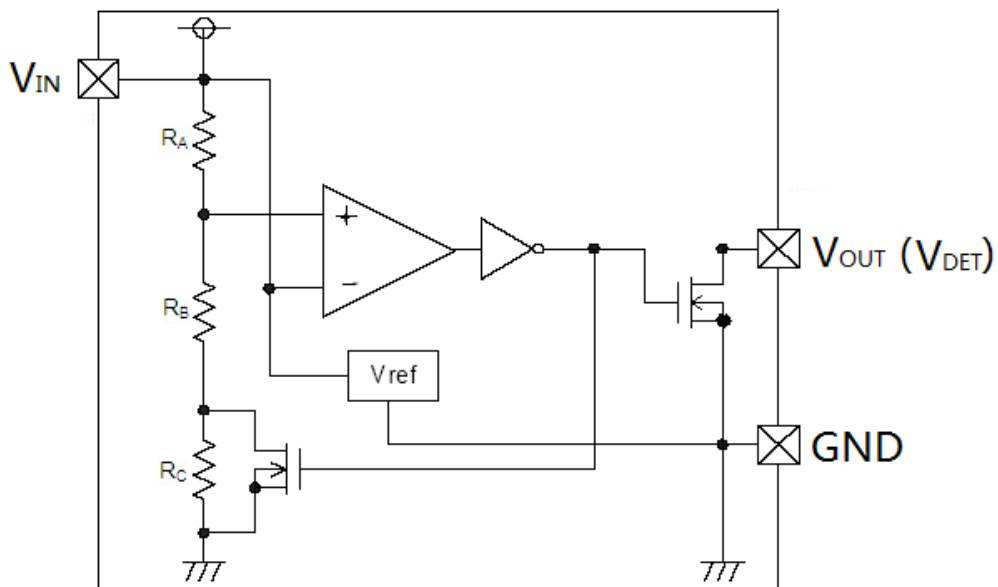


SOT23-5

Pin Assignment

Pin Number					Pin Name	Functions
SOT23	SOT23-3	SOT23-5	SOT89-3	TO-92		
2	2	3	3	3	GND	Ground
1	1	1	1	1	V_{OUT}	Output Voltage
3	3	2	2	2	V_{IN}	Input Voltage
		4			NC	No Connection
		5			NC	No Connection

Block Diagram



Absolute Maximum Ratings

PARAMETER		SYMBAL	RATINGS	UNITS
V _{IN} Input Voltage		V _{IN}	18	V
Output Current		I _{OUT}	50	mA
Output Voltage	NMOS	V _{OUT}	GND-0.3~ V _{IN} +0.3	V
Continuous Total Power Dissipation	SOT23	P _D	250	mW
	SOT23-3/5		300	
	SOT89-3		500	
	TO-92		500	
Operating Ambient Temperature		T _{Opr}	-40~+85	°C
Storage Temperature		T _{stg}	-50~+125	°C
Soldering temperature and time		T _{solder}	260°C, 10s	

Electrical Characteristics (V_{DET} =2.0V to 7.0V ,T_A=25°C ,unless otherwise noted)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Units
V _{DET}	Detect Voltage			V _{DET} ×0.99	V _{DET}	V _{DET} ×1.01	V
V _{HYS}	Hysteresis Width			V _{DET} ×0.02	V _{DET} ×0.05	V _{DET} ×0.1	V
I _{IN}	Operating Current	V _{DET} =2.0V~ 2.8V	V _{IN} =3.0V	-	1.8	3	μA
		V _{DET} =2.8V~ 3.6V	V _{IN} =4.0V	-	1.8	4	
		V _{DET} =3.6V ~ 4.7V	V _{IN} =5.0V	-	2.1	4	
		V _{DET} =4.7V~ 7.0V	V _{IN} =8.0V	-	2.5	4	
V _{IN}	Operating Voltage	V _{DET} =2.0V to 7.0V		0.7	-	18	V
I _{OL}	Output Sink Current	V _{DET} =2.0V~ 2.8V	V _{IN} =-V _{DET(S)} -0.2 V , V _{OUT} =0.2V	0.5			mA
		V _{DET} =2.8V~ 3.6V	V _{IN} =-V _{DET(S)} -0.5 V , V _{OUT} =0.3V	0.5			
		V _{DET} =3.6V ~ 4.7V	V _{IN} =-V _{DET(S)} -0.5 V , V _{OUT} =0.3V	1.2			
		V _{DET} =4.7V~ 7.0V	V _{IN} =-V _{DET(S)} -0.5 V , V _{OUT} =0.3V	2.5			
ΔV _{DET} /ΔT _A	Temperature characteristics	0°C≤T _{opr} ≤70°C			±0.9		mV/°C

- Note:**
- 1、VDF(S) : Specified Detection Voltage value
 - 2、VDF : Actual Detection Voltage value
 - 3、Release Voltage: VDR=VDF+VHYS (ME2808A series)
VDR=VDF-VHYS (ME2808B series)

Functional Description

The ME2808 series is a set of voltage detectors equipped with a high stability voltage reference which is connected to the negative input of a comparator — denoted as V_{REF} in the following figure (Fig. 1). When the voltage drop to the positive input of the comparator (i.e., V_B) is higher than V_{REF} , V_{OUT} goes high, M1 turns off, and V_B is expressed as $V_{BH} = V_{IN} \times (R_B + R_C) / (R_A + R_B + R_C)$. If V_{IN} is decreased so that V_B falls to a value that is less than V_{REF} , the comparator output inverts (from high to low), V_{OUT} goes low, V_C is high, M1 turns on, R_C is bypassed, and V_B becomes: $V_{BL} = V_{IN} \times R_B / (R_A + R_B)$, which is less than V_{BH} . By so doing the comparator out-put will stay low to prevent the circuit from oscillating when $V_B \approx V_{REF}$. If V_{IN} falls below the minimum operating voltage, the output becomes undefined. When V_{IN} goes from low to $V_{IN} \times R_B / (R_A + R_B) > V_{REF}$, the comparator output goes high and V_{OUT} goes high again. The detection voltage is as defined:

$$V_{DET(-)} = (R_A + R_B + R_C) \times V_{REF} / (R_B + R_C)$$

The release voltage is as defined:

$$V_{DET(+)} = (R_A + R_B) \times V_{REF} / R_B$$

The hysteresis width is:

$$V_{HYS} = V_{DET(+)} - V_{DET(-)}$$

Fig.1 demonstrates the NMOS output type with positive output polarity (V_{OUT} is normally high, active low).

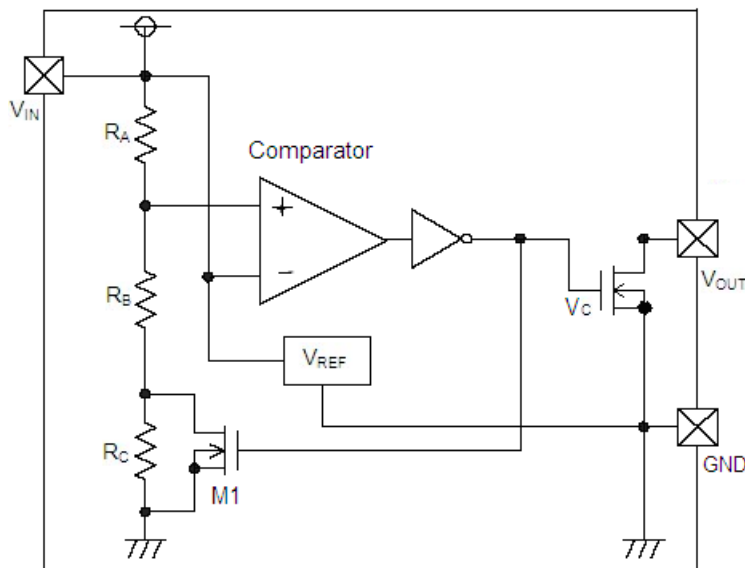
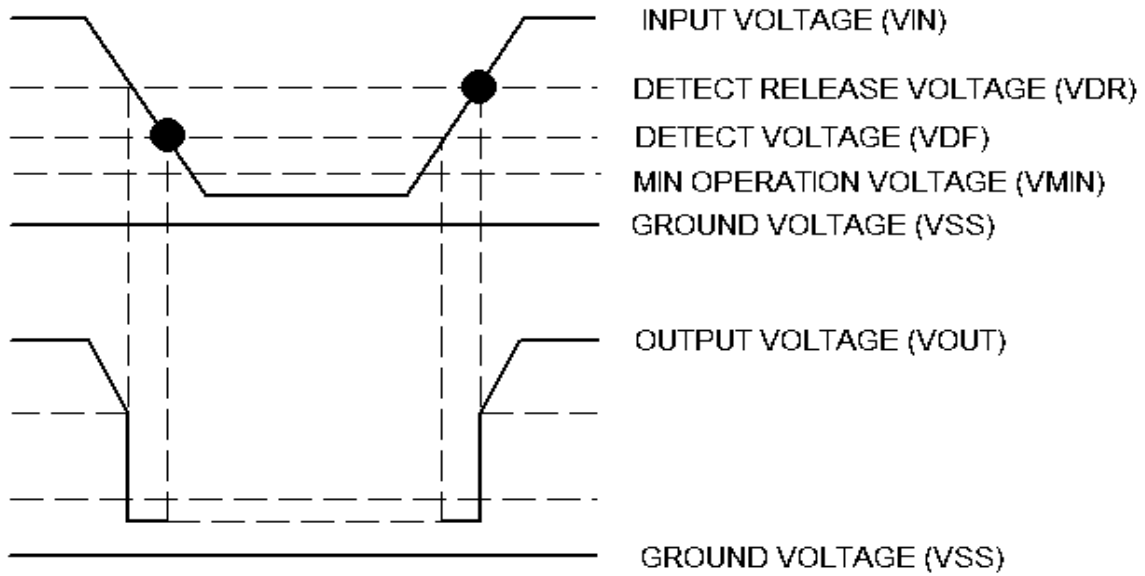


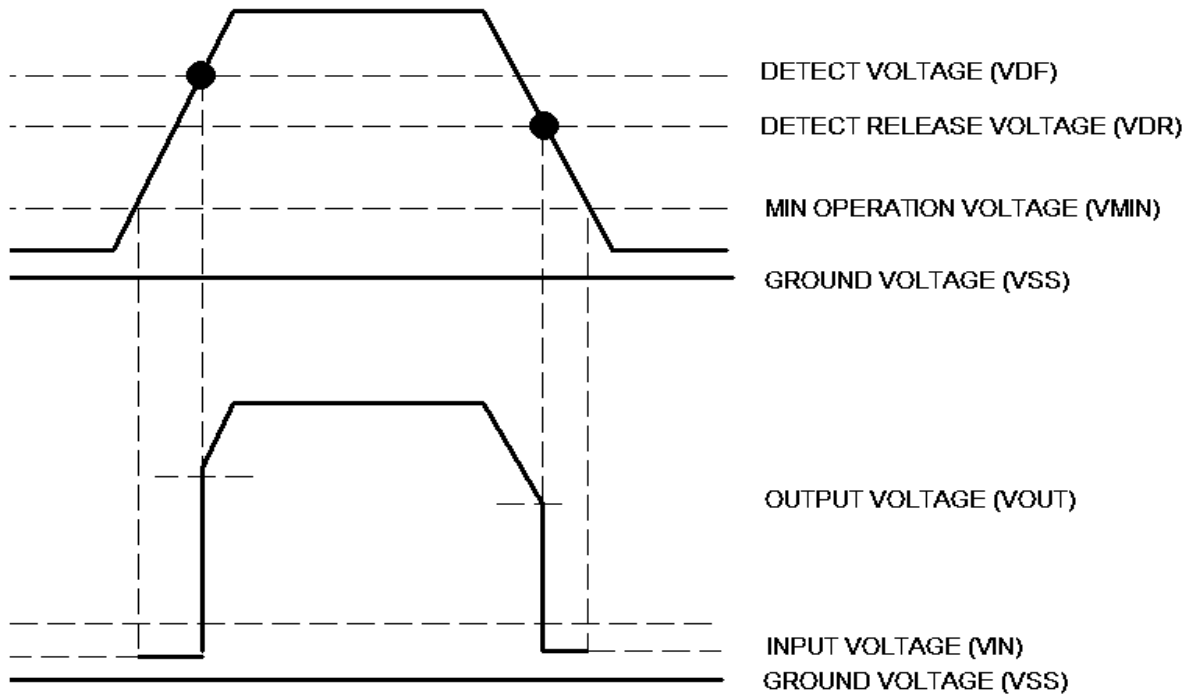
Fig.1 NMOS output voltage detector (ME2808)

Timing Chart

ME2808A:

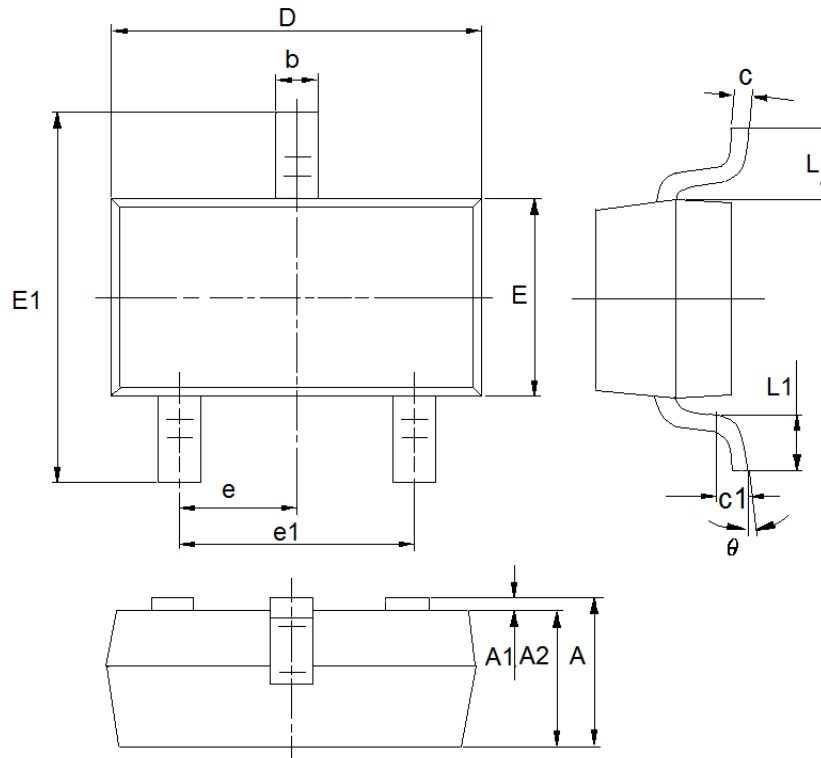


ME2808B:



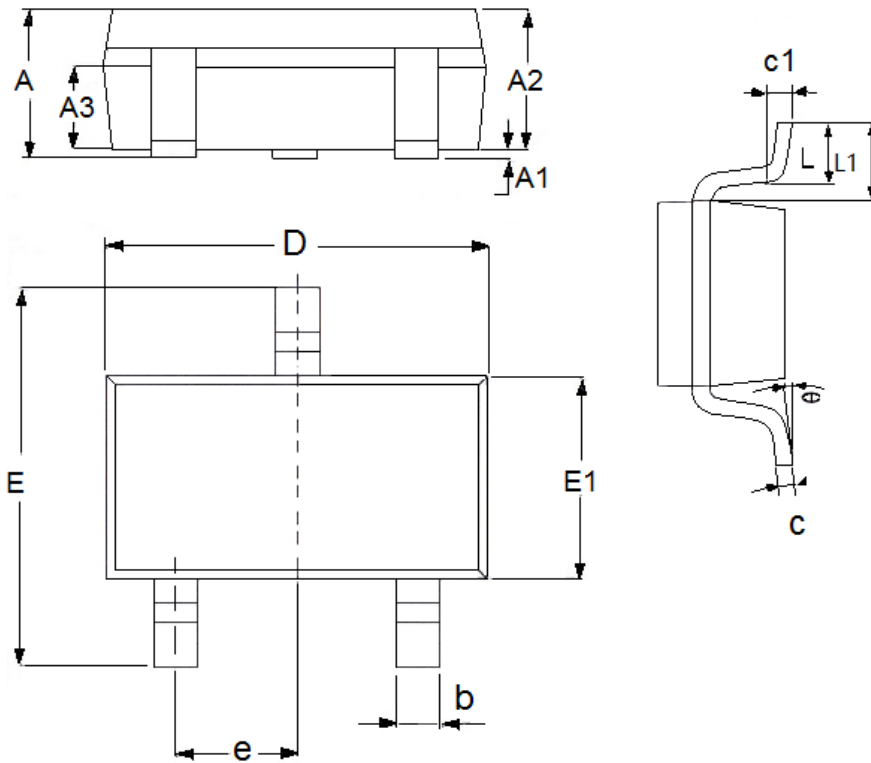
Packaging Information

● SOT23



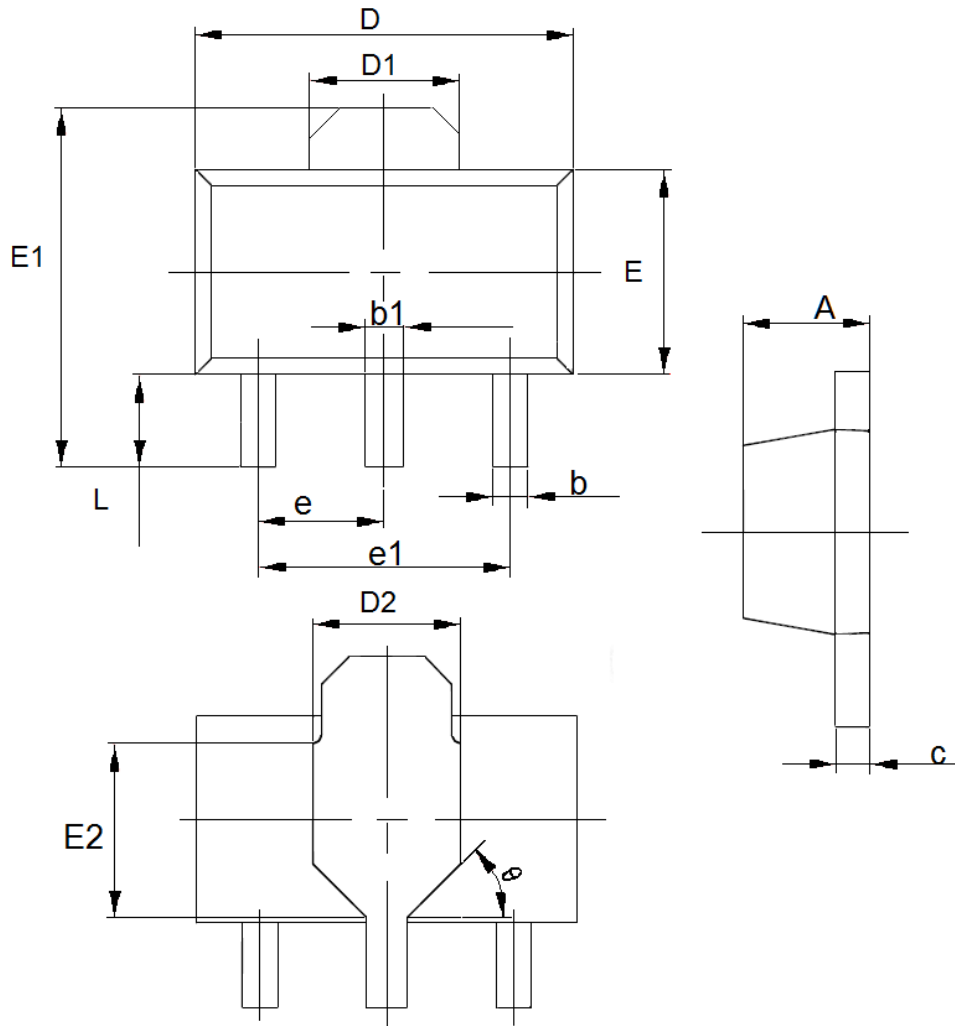
DIM	Millimeters		Inches	
	Min	Max	Min	Max
A	0.9	1.2	0.0354	0.0472
A1	0	0.14	0.0000	0.0055
A2	0.9	1.05	0.0354	0.0413
b	0.28	0.52	0.0110	0.0205
c	0.07	0.23	0.0028	0.0091
D	2.8	3.0	0.1102	0.1181
e1	1.8	2.0	0.0709	0.0787
E	1.2	1.4	0.0472	0.0551
E1	2.2	2.6	0.0866	0.1024
e	0.95(TYP)		0.0374(TYP)	
L	0.55(TYP)		0.0217(TYP)	
L1	0.25	0.55	0.0098	0.0217
θ	0	8°	0.0000	8°
c1	0.25(TYP)		0.0098(TYP)	

● SOT23-3



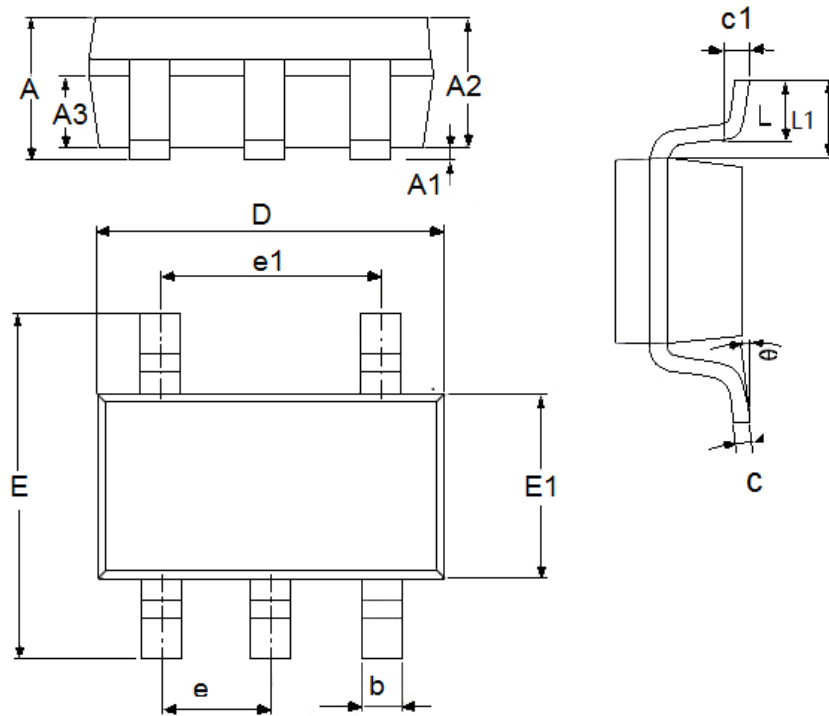
DIM	Millimeters		Inches	
	Min	Max	Min	Max
A	1	1.5	0.0394	0.0591
A1	0	0.15	0.0000	0.0059
A2	0.9	1.3	0.0354	0.0512
A3	0.6	0.7	0.0236	0.0276
b	0.25	0.5	0.0098	0.0197
c	0.1	0.25	0.0039	0.0098
D	2.8	3.1	0.1102	0.1220
E	2.6	3.1	0.1023	0.1220
E1	1.5	1.8	0.0591	0.0709
e	0.95(TYP)		0.0374(TYP)	
L	0.25	0.6	0.0098	0.0236
L1	0.59(TYP)		0.0232(TYP)	
θ	0	8°	0.0000	8°
c1	0.2(TYP)		0.0079(TYP)	
L1	0.59(TYP)		0.0232(TYP)	
θ	0	8°	0.0000	8°
c1	0.2(TYP)		0.0079(TYP)	

● SOT89-3



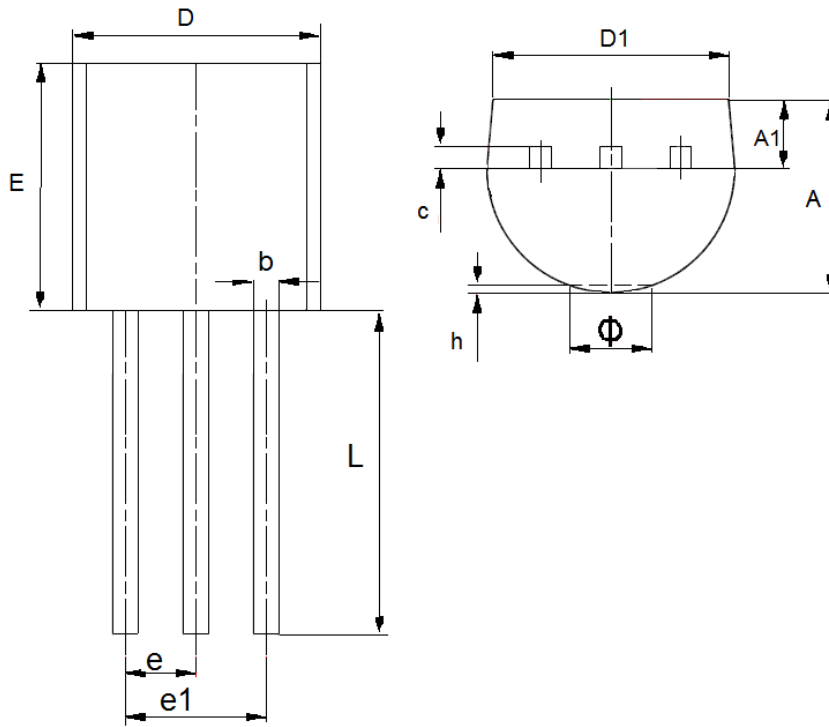
DIM	Millimeters		Inches	
	Min	Max	Min	Max
A	1.4	1.6	0.0551	0.0630
b	0.32	0.52	0.0126	0.0205
b1	0.4	0.58	0.0157	0.0228
c	0.35	0.45	0.0138	0.0177
D	4.4	4.6	0.1732	0.1811
D1	1.55(TYP)		0.061(TYP)	
D2	1.75(TYP)		0.0689(TYP)	
e1	3.0(TYP)		0.1181(TYP)	
E	2.3	2.6	0.0906	0.1023
E1	3.94	4.4	0.1551	0.1732
E2	1.9(TYP)		0.0748(TYP)	
e	1.5(TYP)		0.0591(TYP)	
L	0.8	1.2	0.0315	0.0472
θ	45°		45°	

● SOT23-5



DIM	Millimeters		Inches	
	Min	Max	Min	Max
A	0.9	1.45	0.0354	0.0571
A1	0	0.15	0.0000	0.0059
A2	0.9	1.3	0.0354	0.0512
A3	0.6	0.7	0.0236	0.0276
b	0.25	0.5	0.0098	0.0197
c	0.1	0.26	0.0039	0.0102
D	2.8	3.1	0.1102	0.1220
e1	1.9(TYP)		0.0748(TYP)	
E	2.6	3.1	0.1024	0.1201
E1	1.5	1.8	0.0512	0.0709
e	0.95(TYP)		0.0374(TYP)	
L	0.25	0.6	0.0098	0.0236
L1	0.59(TYP)		0.0232(TYP)	
θ	0	8°	0.0000	8°
c1	0.2(TYP)		0.0079(TYP)	

● TO-92



DIM	Millimeters		Inches	
	Min	Max	Min	Max
A	3.3	3.7	0.1299	0.1457
A1	1.1	1.4	0.0433	0.0551
b	0.38	0.55	0.015	0.0217
c	0.36	0.51	0.0142	0.0201
D	4.3	4.7	0.1693	0.185
D1	3.43	—	0.135	—
E	4.3	4.7	0.1693	0.185
e	1.27TYP		0.05TYP	
e1	2.44	2.64	0.0961	0.1039
L	14.1	14.5	0.5551	0.5709
h	0	0.38	0	0.015
Φ	—	1.6	—	0.063

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